

Crystal Structure, Transport, and Magnetic Properties of an Ir⁶⁺ Compound Ba₈Al₂IrO₁₄

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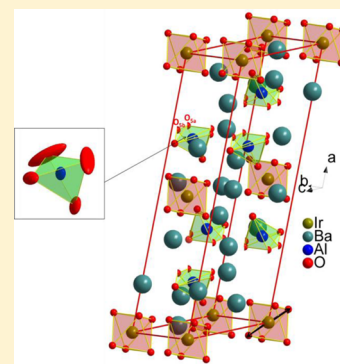
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Supporting Information

ABSTRACT: The novel iridate Ba₈Al₂IrO₁₄ was prepared as single crystals by self-flux method, thereby providing a rare example of an all-Ir(VI) compound that can be synthesized under ambient pressure conditions. The preparation of all-Ir⁶⁺ iridate without using traditional high-pressure techniques has to our knowledge previously only been reported in Nd₂K₂IrO₇ and Sm₂K₂IrO₇. The monoclinic crystal structure (space group C2/m, No.12) is stable down to 90 K and contains layers of IrO₆ octahedra separated by Ba and AlO₄ tetrahedra. The material exhibits insulating behavior with a narrow band gap of ~0.6 eV. The positive Seebeck coefficient indicates hole-like dominant charge carriers. Susceptibility measurement shows antiferromagnetic coupling with no order down to 2 K.



INTRODUCTION

Recently, there has been considerable interest in studying correlated 5d-electron transition metal oxides. Unlike 3d transition metal oxides, 5d materials were expected to be less correlated because of extended orbitals. Therefore, a tendency to metallic behavior was expected. However, experiments have shown that some compounds, such as Sr₃Ir₂O₇, Na₂IrO₃, and Ba₂NaOsO₆, show insulating behavior.^{1–3} Some recent reports show that correlation effects could be important for the 5d insulating transition metal oxides.^{4–6} One example is Ba₃YIr₂O₉,⁷ which crystallizes in a hexagonal structure and transforms into a cubic structure under an applied pressure of 8 GPa at 1273 K; strong spin–orbit coupling (SOC) plays a crucial role in determining the magnetic and insulating properties of this system in both phases.

Iridium-based oxides are relatively unexplored, although they are expected to exhibit interesting physical properties. In the majority of iridium-based compounds Ir⁴⁺ is stabilized, and most of recent theoretical and experimental work has focused on the tetravalent iridates (Ir⁴⁺). On the other hand, Ir⁵⁺ and Ir⁶⁺ can also be obtained under high oxygen pressure conditions, but little attention has been drawn to them.^{8–12}

In this work we show the ambient-pressure synthesis and physical properties of a new all-Ir⁶⁺ iridate Ba₈Al₂IrO₁₄. The preparation of all-Ir⁶⁺ iridate without using traditional high-

pressure techniques has to our knowledge previously only been reported in Nd₂K₂IrO₇ and Sm₂K₂IrO₇.¹³

EXPERIMENTAL SECTION

Synthesis. Single crystals of Ba₈Al₂IrO₁₄ were grown as unexpected byproducts in our attempt to synthesize Ba₃Ir₂YO₉ single crystals. In this process, single crystals of Ba₈Al₂IrO₁₄ were produced by reacting BaCO₃, IrO₂, and Y₂O₃ powder by self-flux method in Al₂O₃ crucible. The mixture of the powders with the ratio of BaCO₃/IrO₂/Y₂O₃ = 26:4:1 was heated for 2 h at 1250 °C and rapidly cooled to room temperature. After the reaction, small black single crystals were found to have a needlelike shape. The maximum dimensions were ~0.5 mm in length and ~0.1 mm in width (Figure 1). The needle axes coincide with the crystallographic *b*-axis. Grinding the black crystals produced brown powder. The crystals are very sensitive to moisture. The chemical composition of the resulting compound was determined using an energy-dispersive X-ray detector (EDX, Oxford Instruments EDX X-MAX). The EDX analysis revealed the presence of Ba, Ir, and Al. We conclude that the raw materials reacted with the Al₂O₃ crucible to acquire Al. This conclusion was supported by inspection of the crucible after reaction, where the crystals could be seen to grow in needles away from the crucible wall. The EDX analysis suggested molar ratios Ba/Al/Ir of 80.1(7):10.3(5):9.6(10), but for these

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Figure 1. Representative single crystals of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$.

numbers the low EDX efficiency for the light element Al must be taken into account.

Structure Determination. Single-crystal X-ray diffraction (XRD) data were measured at room temperature and low temperature (90 K) using Mo $K\alpha$ radiation on a Bruker APEX II CCD diffractometer equipped with a kappa geometry goniometer. The data set was reduced by EvalCCD and then corrected for absorption.^{14,15} The solution and refinement were performed by SHELX.^{16,17} The crystal structure was refined using full-matrix least-squares based on F^2 .

Transport Measurements. Resistivity ρ was measured by a standard four-probe method in the 180–600 K temperature range. Evaporation of chromium/gold contacts on the crystal surface was performed to reduce the contact resistance. To measure Seebeck coefficient S the sample was placed on a ceramic bar, at one end of which a small heater was anchored to generate heat, which was sent through the crystal. The temperature gradient across the specimen was measured by a differential Chromel–Constantan thermocouple. The Seebeck coefficient was evaluated in the 300–680 K temperature range due to the high resistance of our crystal.

Optical Measurements. Optical measurements were performed at room temperature. Transmission and reflectivity were measured in the range from 0.15 to 0.5 eV and complemented by spectroscopic ellipsometry from 0.5 to 2.6 eV.

Magnetization Measurements. The magnetic susceptibility $\chi(T) = M(T)/H$ at constant H was measured using a superconducting quantum interference device (SQUID) magnetometer in the 2–300 K temperature range with $H = 0.1, 1,$ and 5 T applied both parallel and perpendicular to the b -axis employing both zero-field cooling (ZFC) and field-cooling (FC) protocols. The isothermal magnetization $M(H)$ was measured for $T = 2, 5,$ and 10 K in fields up to $H = 5$ T. Measurements were made on an aligned stack of dozens of needles with a total mass of 7.0 mg. All b -axis coincided, whereas measurements with $H \perp b$ hence measure an average over direction perpendicular to b -axis.

RESULTS AND DISCUSSION

Crystal Structure. According to the systematic absences of the XRD reflections, the space groups $C2/m$, Cm , and $C2$ can be suggested. The structure refinements were performed for all these space groups and finalized with nearly the same reliability factor $R_1 \approx 4\%$. Therefore, the highest symmetric space group, $C2/m$ (No.12) was selected.

The lattice parameters were determined as $a = 19.8367(14)$, $b = 5.9709(6)$, $c = 7.6138(7)$ Å, $\alpha = \gamma = 90^\circ$, and $\beta = 109.785(5)^\circ$. The longest size of the needlelike crystals coincides with the b -axis. Further details of the data collection, structure determination, and refinement are listed in Tables 1 and 2. The crystal structure of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ is shown in Figure 2, where the IrO_6 octahedra and AlO_4 tetrahedra are outlined.

The crystal structure of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ is related to $\text{Sr}_8\text{Si}_2\text{PtO}_{14}$, reported in ref 18 with asymmetric space group $C2$ (No. 5), $a =$

Table 1. Details of the Data Collection and Structure Refinement for $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ ^a

| | | |
|--|---|---|
| empirical formula | $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ | |
| formula weight (g/mol) | 1568.88 | |
| temperature (K) | 293(2) | 90(2) |
| unit cell dimensions (Å, deg) | $a = 19.8367(14)$, $b = 5.9709(6)$ $c = 7.6138(7)$; $\beta = 109.785(5)$ | $a = 19.8283(15)$, $b = 5.9591(5)$ $c = 7.6013(5)$; $\beta = 109.656(5)$ |
| volume (Å ³) | 848.57(13) | 845.82(11) |
| calculated density (g/cm ³) | 6.140 | 6.160 |
| absorption coefficient (mm ⁻¹) | 26.212 | 26.297 |
| $F(000)$ | 1326 | |
| θ range for data collection (deg) | 3.58–34.98 | 3.59–35.00 |
| index ranges | $-32 \leq h \leq 30$, $-9 \leq k \leq 9$, $-12 \leq l \leq 12$ | |
| reflections collected/unique | 10 716/2019 $R_{\text{int}} = 0.0564$ | 12095/2014 $R_{\text{int}} = 0.0537$ |
| completeness to 2θ | 99.8% | 99.8% |
| data/restraints/parameters | 2019/0/64 | 2014/0/64 |
| goodness-of-fit on F^2 | 1.133 | 1.110 |
| final R indices [$I > 2\sigma(I)$] | $R_1 = 0.0390$, $wR_2 = 0.0918$ | $R_1 = 0.0392$, $wR_2 = 0.0791$ |
| R indices (all data) | $R_1 = 0.0442$, $wR_2 = 0.0949$ | $R_1 = 0.0455$, $wR_2 = 0.0821$ |

^aThe diffraction study was performed at 293(2) and 90(2) K using Mo $K\alpha$ radiation with $\lambda = 0.71073$ Å. The lattice is monoclinic, $C2/m$ space group, with $Z = 2$. A full-matrix least-squares method was employed to optimize F^2 .

$18.830(2)$, $b = 5.744(1)$, $c = 7.172(1)$ Å, and $\beta = 110.72(1)^\circ$. Both structures contain identical number, 50, of atoms per similar unit cell, and they can be described with the same type of cationic polyhedra (Figure 2). Isolated AlO_4 tetrahedra (SiO_4 in $\text{Sr}_8\text{Si}_2\text{PtO}_{14}$) and IrO_6 octahedra (PtO_6 in $\text{Sr}_8\text{Si}_2\text{PtO}_{14}$) are separated by Ba ions (Sr ions in $\text{Sr}_8\text{Si}_2\text{PtO}_{14}$). The IrO_6 octahedra are slightly distorted with two 2.041(7) Å long and four 1.970(5) Å short Ir–O distances (Table 2). The structure refinement yields very large anisotropic displacement parameters (ADP) for one oxygen atom, O5a, in the AlO_4 tetrahedra (inset of Figure 2). A reduced occupancy of the O5a site is unreasonable because the Al tetrahedron is a strong unit from which it is highly unlikely that an oxygen can be removed. Furthermore, allowing reduced occupancy on this site in the refinement does not remove the large elongation of the ADP ellipsoid. Anharmonic atomic displacement of O5a was also excluded because no reduction of its atomic displacements can be observed in the structure obtained at 90 K. We therefore conclude that rather than thermal motion, this oxygen is split between two nearby positions, O5a and O5b (Figure 2). The splitting of O5a and O5b can also be explained from the consideration of the first coordination spheres of Ba3 and Al1 (Table 2). Two positions of O5a are necessary to form Ba3 octahedron with 2.5755(6) Å short distances between Ba3 and O5a, while the O5b positions cannot compensate a charge Ba due to the 3.1308(7) Å long distances between Ba3 and O5b. On the other hand, two O5b positions are necessary to form Al1-tetrahedron with 1.628(3) Å short distances between Al1 and O5b, while the O5a is too far from Al1 (with 1.8740(13) Å long distances between Al1 and O5a). Therefore, statistical

Table 2. Selected Interatomic Distances (Å) for Ba₈Al₂IrO₁₄

| atom ₁ | atom ₂ | count | <i>d</i> 1,2 [Å] | atom ₁ | atom ₂ | count | <i>d</i> 1,2 [Å] |
|-------------------|-------------------|-------|------------------|-------------------|-------------------|------------|------------------|
| Ir1 | O3 | 4× | 1.970(5) | Ba3 | O4 | 1× | 2.924(12) |
| | O2 | 2× | 2.041(7) | | O4 | 2× | 3.0196(18) |
| Ba1 | O1 | 1× | 2.739(13) | Ba4 | O5b | 2× | 3.1308(7) |
| | O4 | 1× | 2.750(11) | | O5a | 2× | 2.5755(7) |
| | O1 | 1× | 2.750(11) | O2 | 1× | 2.610(8) | |
| | O3 | 2× | 2.767(5) | O3 | 2× | 2.813(5) | |
| | O3 | 2× | 2.868(5) | O5b | 2× | 2.8676(6) | |
| Ba2 | O2 | 2× | 2.9960(7) | O1 | 2× | 3.040(2) | |
| | O5b | 2× | 2.5396(5) | O2 | 1× | 3.052(7) | |
| | O5a | 2× | 2.6044(5) | Al1 | O5b | 2× | 1.628(3) |
| | O4 | 1× | 2.698(12) | | O4 | 1× | 1.724(12) |
| | Ba3 | O3 | 2× | 2.712(5) | O1 | 1× | 1.707(13) |
| O5b | | 2× | 2.9292(6) | O5a | 2× | 1.8740(13) | |
| O1 | | 1× | 2.995(13) | O5a | O5b | 1× | 0.8292(1) |
| O5a | | 2× | 2.5755(6) | Ir1 | Ba4 | 2× | 3.3884(8) |
| O2 | | 1× | 2.686(8) | | Ba3 | 2× | 3.4534(7) |
| | O3 | 2× | 2.863(5) | Ba1 | 2× | 3.4913(4) | |

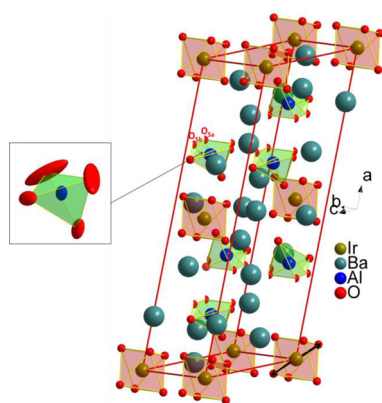


Figure 2. Crystal structure of Ba₈Al₂IrO₁₄. Red and green polyhedra indicate IrO₆ octahedra and AlO₄ tetrahedra, respectively. The black arrows mark the long axis direction of the elongated octahedra. The unit cell is outlined in red. (inset) AlO₄ tetrahedron with the extremely large ADP ellipsoid of nonsplit oxygen atom with atomic displacement ellipsoids at 50% probability. Split atoms, O5a and O5b, are shown with half spheres indicating their occupation of 50%.

occupation of O5a and O5b is a solution of the situation. Refinements allowing a variable occupancy on O2 and O3 in the IrO₆ octahedra yielded 100% (Table 3).

The oxidation state of metal ions in solids may be estimated using an empirical quantity, known as the bond valence sum (BVS), which is based on statistics of crystallographically determined metal–ligand bond distance. V_i , the effective valence or BVS of the *i*th atom, is determined by

$$V_i = \sum_j S_{ij} = \sum_j \exp[(r_0 - r_{ij})/0.37] \quad (1)$$

where r_0 is empirically determined for each *i*–*j* atomic pair, and r_{ij} is the observed interatomic distance between the *i*th and *j*th atom in the material under consideration. S_{ij} can be considered

to be the effective charge in the r_{ij} bond. V_i is then obtained as the sum over *j* of all of the S_{ij} . Reference 13 reported two all-Ir⁶⁺ containing oxides, namely, Nd₂K₂IrO₇ (Ir–O distance 1.982 Å) and Sm₂K₂IrO₇ (Ir–O distance 1.972 Å), prepared under ambient pressure. Using these two compounds the average r_0 for Ir⁶⁺–O is 1.977 Å. For Ba₈Al₂IrO₁₄, the four 1.970 Å bonds and the two 2.041 Å bonds (Table 2) give a BVS of 5.76(9) for Ir, suggesting that Ir(VI) is the most likely oxidation state—in agreement with the stoichiometry obtained from crystallography.

Transport Properties. The electrical resistivity ρ of Ba₈Al₂IrO₁₄ measured in the 180–600 K temperature range is shown in Figure 3a. The resistivity value is 7.3 kΩ cm at room temperature, and ρ increases monotonically as temperature decreases ($d\rho/dT < 0$), revealing the insulating nature of this compound. In the inset of Figure 3a, we show $d(\ln\rho)/d(e/k_B T)$ versus T . Thermally activated behavior is observed above 350 K. In this temperature range $\rho(T)$ can be described by the formula

$$\rho(T) = \rho_0 \exp(E_a/k_B T) \quad (2)$$

where ρ_0 is a parameter depending on the sample characteristics, k_B is Boltzmann's constant, T is absolute temperature, and E_a denotes the thermal activation energy of electrical conduction. It yielded the activation energy $E_a = 0.290 \text{ eV} \pm 0.005 \text{ eV}$. In this case, a rough estimate of band gap energy $E_g = 2E_a$ is $0.58 \text{ eV} \pm 0.01 \text{ eV}$ above 350 K. At lower temperature, the resistivity deviates from activated behavior.

As shown in Figure 3b, the Seebeck coefficient S of Ba₈Al₂IrO₁₄ is positive in the whole temperature range, suggesting hole-dominated conduction. At room temperature, $S = 7500 \mu\text{V/K}$. S further decreases with temperature increasing, as expected for insulators, and changes gradually with no clear transition temperature in the temperature range of 300–500 K and 620–680 K.

Table 3. Atomic Occupancy for Ba₈Al₂IrO₁₄

| Ir1 | Ba1 | Ba2 | Ba3 | Ba4 | Al1 | O1 | O2 | O3 | O4 | O5a | O5b |
|-----|----------|----------|----------|----------|-----------|---------|---------|-----------|---------|---------|---------|
| 1 | 1.006(2) | 1.007(2) | 1.011(2) | 1.001(3) | 0.974(11) | 0.99(2) | 1.03(2) | 1.031(14) | 1.02(3) | 0.46(2) | 0.51(2) |

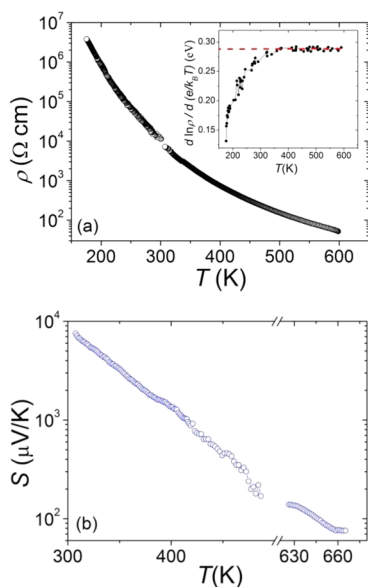


Figure 3. (a) Electrical resistivity of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$. (inset) $d(\ln\rho)/d(e/k_B T)$ vs T . The red dashed line is the guide to eyes of this fitting. $E_a \approx 0.29$ eV is estimated above 350 K in this plot. (b) The temperature dependence of the Seebeck coefficient of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$.

Optical Properties. The optical transmission and reflectivity are shown in Figure 4a from 0.15 to 0.5 eV at room

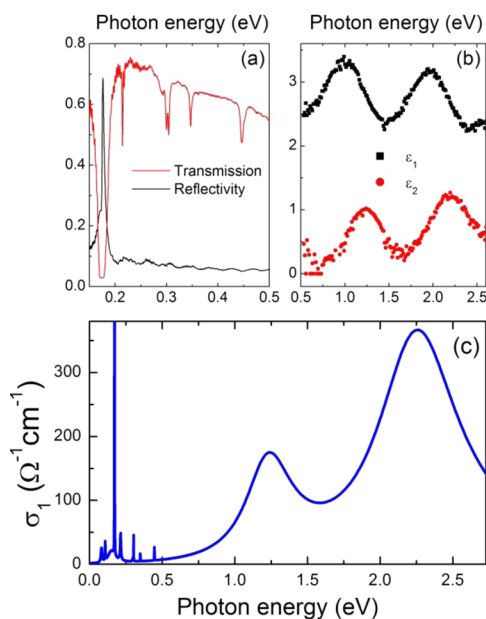


Figure 4. (a) Transmission and reflectivity spectra as a function of photon energy for $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ at room temperature. (b) The real and imaginary part of the dielectric function. (c) The real part of optical conductivity, $\sigma_1(\omega)$, modeled from the transmission, reflectivity, and ellipsometry data, shown at 300 K.

temperature. The low reflectivity and the high transmission indicate the insulating behavior in this material. These two quantities are related to the dielectric function $\epsilon = \epsilon_1 + i\epsilon_2$. Figure 4b shows the real and imaginary part of the dielectric function, ϵ_1 and ϵ_2 , as determined by the ellipsometry from 0.5 to 2.6 eV. By simultaneously fitting the above optical quantities, one obtains an estimate of the complex dielectric function ϵ ,

and from it the real part of the optical conductivity, $\sigma_1(\omega)$, is shown in Figure 4c. The conductivity $\sigma_1(\omega)$ is gapped below ~ 0.7 eV, indicating the insulating behavior of this material, which is in accordance with the results of resistivity. Below the gap, several sharp oscillations are seen, which can be attributed to vibrational phonon modes. Two strong absorptions can be seen above the gap, centered at 1.2 and 2.2 eV, which are likely intraband transitions.

Magnetic Properties. The temperature dependence of magnetic susceptibility parallel to the b -axis of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$, measured in applied magnetic fields of 0.1, 1, and 5 T, is shown in Figure 5a. The susceptibility increases monotonically with decreasing temperature and shows no indication of long-range order. The zero-field cooling (ZFC) and field-cooling (FC) data completely overlay at all temperatures down to 2 K. The susceptibilities that are, respectively, parallel and perpendicular to the b -axis are compared in Figure 5b, showing the magnetic anisotropy of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$.

To analyze the T dependence of the anisotropic susceptibility quantitatively, we plotted $(M/H)_\perp(T)$ versus $(M/H)_\parallel(T)$ with an implicit parameter T in the inset of Figure 5b. The analysis mentioned in ref 19 leads to the relation between $\chi_\parallel(T)$ and $\chi_\perp(T)$:

$$\chi_\perp(T) = (g_\perp/g_\parallel)^2 \chi_\parallel(T) + [\chi_0^\perp - (g_\perp/g_\parallel)^2 \chi_0^\parallel] \quad (3)$$

The main point of this analysis is that the fitted slope of the data corresponds to the ratio $(g_\perp/g_\parallel)^2$. $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ has the anisotropy of $(g_\perp/g_\parallel)^2 = 0.50(5)$.

Further fitting the data above 50 K to a modified Curie–Weiss (CW) law

$$\chi(T) = C/(T - \theta) + \chi_0 \quad (4)$$

yielded a Curie–Weiss constant $C = 0.23(1)$ emu/(mol K), an effective moment $\mu_{\text{eff}} = 1.36(3)$ μ_B per formula unit, a Curie temperature $\theta = -10(1)$ K and a temperature independent term $\chi_0 = 1.15 \times 10^{-3}$ emu/mol for $H \parallel b$ (parallel to the needle direction) and $C = 0.16(1)$ emu/(mol K), $\mu_{\text{eff}} = 1.13(4)$ μ_B per formula unit, $\theta = -32(2)$ K and $\chi_0 = 2.59 \times 10^{-3}$ emu/mol for $H \perp b$ (perpendicular to the needle direction).

The negative Curie temperature θ indicates antiferromagnetic (AFM) coupling. The anisotropy obtained from Curie–Weiss fitting is $(\mu_{\text{eff}\perp}/\mu_{\text{eff}\parallel})^2 = 0.69(8)$, which is in same direction but numerically different from the $(g_\perp/g_\parallel)^2 = 0.50(5)$ in the plot of $(M/H)_\perp(T)$ versus $(M/H)_\parallel(T)$. This is because the latter assumes same functional form for $(M/H)_\perp(T)$ and $(M/H)_\parallel(T)$, which is not the case if θ is anisotropic. The anisotropic Curie–Weiss constant C indicates the magnetic anisotropy of this compound, which can be understood from an anisotropic g -factor, as we discussed before. The temperature independent term χ_0 is rather large and anisotropic, but similar large and anisotropic values have been reported for other compounds, such as NaIrO_3 , $\text{Pr}_2\text{Ir}_2\text{O}_7$ and $\text{Na}_x\text{CoO}_2 \cdot y\text{H}_2\text{O}$.^{19–21}

The Ir^{6+} ions sit in an octahedral crystal field generated by the neighboring O^{2-} ions splitting the 5d orbitals into higher e_g and lower t_{2g} levels. The electronic configuration of the Ir^{6+} being $5d^3$ the t_{2g} crystal field levels are half occupied, and the Hund coupling selects the high-spin $S = 3/2$ state. However, the effective moment for a spin-3/2 isotropic paramagnet is $\mu_{\text{eff}} = 3.87$ μ_B far larger than the observed $\mu_{\text{eff}} = 1.36$ μ_B . The strong SOC present in the Ir 5d orbitals ($\lambda_{\text{SO}} \approx 400$ meV) has been shown to lead to such a reduction of the $5d^3$ effective magnetic

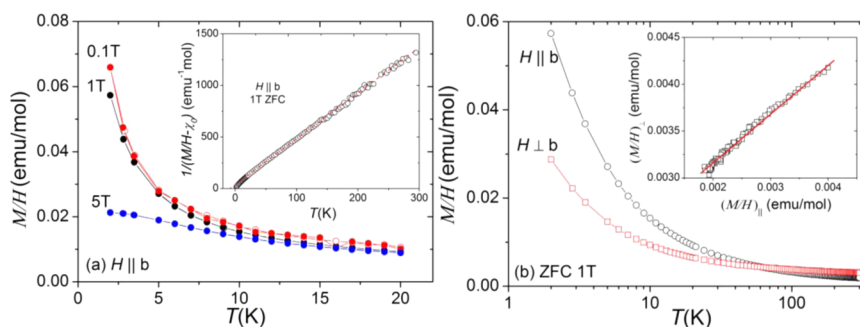


Figure 5. (a) Temperature dependence of M/H , which approximates the magnetic susceptibility except below 10 K where $M(T)$ starts to deviate from linearity of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ under various fields applied parallel to the b -axis. Both ZFC and FC data are shown. (inset) Inverse magnetic susceptibility $1/(M/H - \chi_0)$ versus temperature T in a magnetic field $H = 1$ T (ZFC). (b) Temperature-dependent magnetic susceptibility of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ under $H = 1$ T applied perpendicular and parallel to the b -axis, respectively, in ZFC. (inset) (M/H) versus $(M/H)_||$.

moment, while the tetragonal distortion of the octahedron will further reduce it.^{22–24} Comparing the measured effective moment with the one for an isotropic $S = 3/2$ paramagnet, we have for $H \parallel b$

$$\mu_{\text{eff}} = g\sqrt{S(S+1)}\mu_B = 1.36\mu_B \quad (5)$$

yielding a reduced g -factor $g_{\parallel} = 0.58$.

The magnetic field dependence H applied parallel to the b -axis of the magnetization of $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$, measured at different temperatures, is shown in Figure 6. The dashed lines are

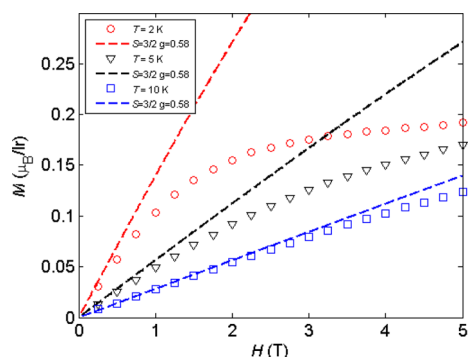


Figure 6. Isothermal magnetization M versus magnetic field H applied parallel to the b -axis at various temperatures T . The dashed lines are fits to the Brillouin functions for $S = 3/2$, $g = 0.58$.

fits to the Brillouin functions for $S = 3/2$, $g = 0.58$. The $M(H)$ data above $T = 10$ K follow the Brillouin function, indicating the absence of any ferromagnetic impurities in the material. At lower T , $M(H)$ values become gradually smaller than the Brillouin function, indicating dominant antiferromagnetic coupling.

CONCLUSIONS

We synthesized a new compound $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ and systematically studied its crystal structure and transport, optical, and magnetic properties. It has been prepared as single crystals by self-flux method, thereby providing a rare example of an all-Ir(VI) compound that can be synthesized under ambient pressure conditions. Our experiment shows $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ has monoclinic crystal structure with the space group of $C2/m$ (12). It is a p -type band insulator with a narrow band gap of ~ 0.6 eV, and these are confirmed by the optical measurements. Furthermore, $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$ shows antiferromagnetic couplings but displays no order down to 2 K. We hope this work will

stimulate more investigations on these Ir-based materials that offer a wide window into the research of spin–orbit interactions and the strength of electronic correlations.

ASSOCIATED CONTENT

Supporting Information

Crystallographic files in CIF format for $\text{Ba}_8\text{Al}_2\text{IrO}_{14}$. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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Notes

The authors declare no competing financial interest.

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